

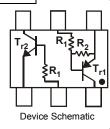


DUAL PRE-BIASED TRANSISTORS FOR POWER MANAGEMENT

Features

- **Epitaxial Planar Die Construction**
- **Built-In Biasing Resistors**
- One 500mA PNP and One 100mA NPN
- Lead Free/RoHS Compliant (Note 1)
- "Green" Devices (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Part Numb	er	R1	R2	Marking
DIMD10A	Tr1	0.1K	10K	C73
DIVIDIUA	Tr2	10K	-	073



Mechanical Data

- Case: SC-74R
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Table and Page 3
- Ordering Information: See Page 3
- Weight: 0.015 grams (approximate)

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Maximum Ratings PNP Section Tr1 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	Vcc	-50	V
Input Voltage	V _{IN}	-5 to +5	V
Output Current	lo	-500	mA

Maximum Ratings NPN Section Tr2 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	lc	100	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation	PD	300*	mW
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

* Not to exceed 200mW for either Tr1 or Tr2.

Electrical Characteristics PNP Section Tr1 @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	-0.3		_	V	V _{CC} = -5V, I _O = -100μA
Input voltage	V _{l(on)}	_	_	-1.5		V _O = 0.3, I _O = -100mA
Output Voltage	V _{O(on)}	_	-0.1	-0.3	V	I _O = -100mA/-5mA
Input Current	lı –	_	_	-25	mA	V ₁ = -2V
Output Current	I _{O(off)}	_		-0.5	μA	$V_{CC} = -50V, V_1 = 0V$
DC Current Gain	GI	68	_	—		_
Gain-Bandwidth Product*	f _T	_	200		MHz	V _{CE} = -10V, I _E = -50mA, f = 100MHz

* Transistor - For Reference Only

1. No purposefully added lead. Notes:

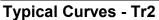
2. "Green" devices, Halogen and Antimony Free, Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

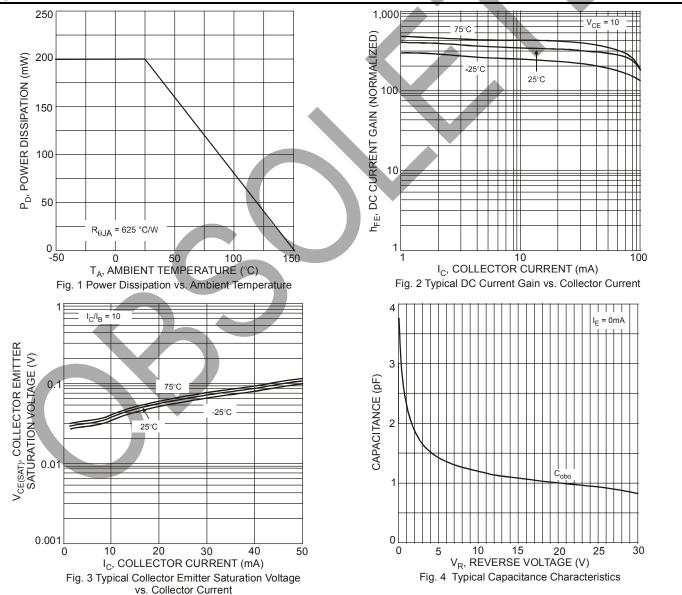


Electrical Characteristics NPN Section Tr2 @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50			V	I _C = 50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	50			V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5			V	I _E = 50μA
Collector Cutoff Current	I _{CBO}			0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	I _{EBO}	_	_	0.5	μΑ	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	0.3	V	I _C /I _B = 10mA / 1.0mA
DC Current Transfer Ratio	h _{FE}	100	250	600	_	I _C = 1mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 3)	f _T	_	250		MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

Notes: 3. Transistor - For Reference Only

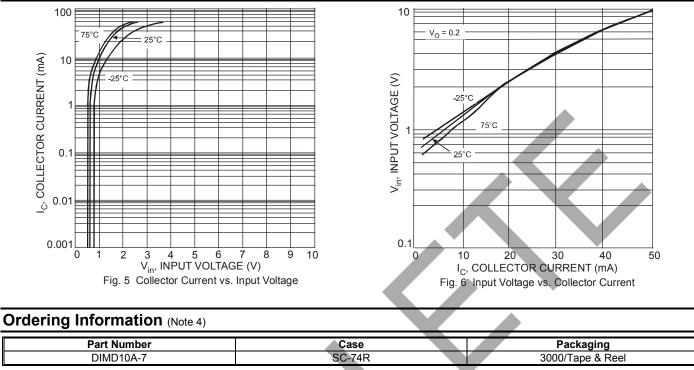






DIMD10A

Typical Curves - Tr2 (continued)

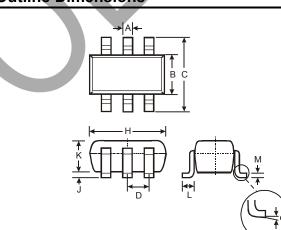


Notes: 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

				C73	¥ ∖	C73 = Proc YM = Date Y = Year (e M = Month	Code N ex: S = 2	larking 2005)	-			
e Code Key			٦	TT			(07. 0 -	ocpten				
e Code Key Year	2005	2006	2007	2008	2009	2010	`	011	2012	2013	2014	2015
	2005 S	2006 T	2007 U	2008			2		, 	2013 A	2014 B	2015 C
Year		2006 T Feb	2007 U Mar	2008 V Apr	2009	2010	2	011	, 		-	

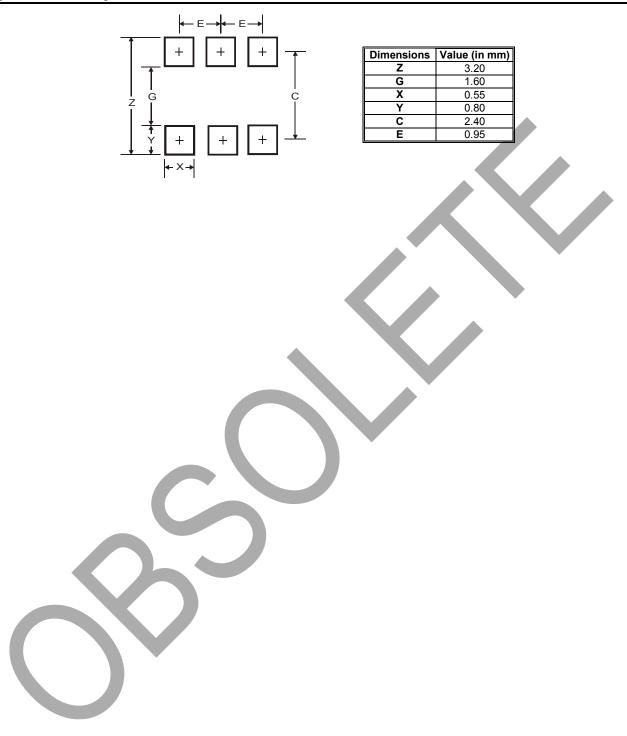
Package Outline Dimensions



	SC-7	74R	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	_		0.95
н	2.90	3.10	3.00
J	0.013	0.10	0.05
κ	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
α	0°	8°	
All D	imensi	ons in	mm



Suggested Pad Layout





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